

Review of: "This phenomenon is the basis of the work of some electronic components and some nanoscopes. But in nanotransistor"

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^{[1][2]} An increase in the surface-to-volume ratio and changes in geometry and electronic structure have a strong impact on the chemical interactions of matter. For example, the activity of small particles changes with changes in the number of atoms (and thus the size of the particles). Unlike today's nano-transistors, which behave based on the movement of a mass of electrons in matter, new devices follow the phenomena of quantum mechanics at the nano scale, in which the discrete nature of electrons cannot be ignored. By reducing all the horizontal and vertical dimensions of the transistor, the electric charge density increases in different areas of the nano-transistor, or, in other words, the number of electric charges per unit area of the nano-transistor increases.

This has two negative consequences:

First, with the increase in electric charge density, the possibility of electric charge discharge from the insulating areas of the transistor increases, and this causes damage to the transistor and its failure. This event is similar to the discharge of excess electric charge between the cloud and the ground in the phenomenon of lightning, which causes the ionization of air molecules into negative and positive ions. Secondly, with the increase of the electric charge density, the electrons may leave the range of the radius of one atom and enter the range of the neighboring atom's radius under the influence of repulsive or abduction forces, which have now increased in value. This is called tunneling in quantum physics. Electron tunneling from one atom to the adjacent atom is a phenomenon that happens a lot between electrons in small dimensions.

This phenomenon is the basis of the work of some electronic components and some nanoscopes. But in a nanotransistor, this phenomenon is not a useful phenomenon because electron tunneling from one atom to the adjacent atom may continue and cause an electric current.

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